

# **TOSHIBA CORPORATION**

Semiconductor Company

## **Important Notices**

Thank you for your continued patronage of Toshiba microcontrollers.

This page gives you important information on using Toshiba microcontrollers. Please be sure to check each item for proper use of our products.

#### **TMP87PM75**

TOSHIBA Microcontrollers 870 Family (TMP87CH75) (TMP87CM75) (TMP87PM75)

# Datasheet Modifications: I<sup>2</sup>C Bus Mode Control

The following problem is included in the explanation of the  $I^2C$  bus function of this data sheet. It will guide the correction as follows. Please read it for the explanation of this data sheet as follows.

#### Section: "I<sup>2</sup>C Bus Mode Control"

#### • In the explanation of the Serial Bus Interface Control Register 1

- 1. Delete the setting examples where the serial clock frequency exceeds 100 kHz.
- 2. Add the following note.

SCK         Serial clock selection         010:57.1 011:29.9 100:15.3 101:7.72         kHz kHz kHz kHz         at fc = 8MHz (Output on SCL pin)         Write on           100:15.3         kHz 110:3.88         kHz         (Output on SCL pin)         on	011 : 29.9 kHz at fc = 8MHz
--	-----------------------------

Note: This I<sup>2</sup>C bus circuit does not support the Fast mode. It supports the Standard mode only. Although the I<sup>2</sup>C bus circuit itself allows the setting of a baud rate over 100 kbps, the compliance with the I<sup>2</sup>C specification is not guaranteed in that case.

In "(3) Serial clock"

1. Add the following sentence about the communication baud rate.

a. Clock source

The SCK (bits 2 to 0 in the SBICR1) is used to select a maximum transfer frequency outputed on the SCL pin in the master mode. Set a communication baud rate that meets the  $I^2C$  bus specification, such as the shortest pulse width of  $t_{LOW}$ , based on the equations shown below.

Four or more machine cycles are required for both the high and low levels of the pulse width of a clock which is input externally in both the master and slave mode.

$$\begin{split} t_{LOW} &= 2^n/f_C \\ t_{HIGH} &= 2^n/f_C + 12/f_C \\ fscl &= 1/(t_{LOW} + t_{HIGH}) \end{split}$$

# **Document Change Notification**

The purpose of this notification is to inform customers about the launch of the Pb free version of the device. The introduction of a Pb-free replacement affects the datasheet. Please understand that this notification is intended as a temporary substitute for a revision of the datasheet.

Changes to the datasheet may include the following, though not all of them may apply to this particular device.

- 1. Part number
  - Example: TMPxxxxxF TMPxxxxxFG

All references to the previous part number were left unchanged in body text. The new part number is indicated on the prelims pages (cover page and this notification).

2. Package code and package dimensions

Example: LQFP100-P-1414-0.50C LQFP100-P-1414-0.50F

All references to the previous package code and package dimensions were left unchanged in body text. The new ones are indicated on the prelims pages.

3. Addition of notes on lead solderability

Now that the device is Pb-free, notes on lead solderability have been added.

4. RESTRICTIONS ON PRODUCT USE

The previous (obsolete) provision might be left unchanged on page 1 of body text. A new replacement is included on the next page.

5. Publication date of the datasheet

The publication date at the lower right corner of the prelims pages applies to the new device.

#### 1. Part number

#### 2. Package code and dimensions

Previous Part Number (in Body Text)	Previous Package Code (in Body Text)	New Part Number	New Package Code	OTP
TMP87PM75F	P-QFP100-1420-0.65A	TMP87PM75FG	QFP100-P-1420-0.65A	—

\*: For the dimensions of the new package, see the attached Package Dimensions diagram.

#### 3. Addition of notes on lead solderability

The following solderability test is conducted on the new device

#### Lead solderability of Pb-free devices (with the G suffix)

Test	Test Conditions	Remark
Solderability	<ul> <li>(1) Use of Lead (Pb)</li> <li>solder bath temperature = 230°C</li> <li>dipping time = 5 seconds</li> <li>the number of times = once</li> <li>use of R-type flux</li> <li>(2) Use of Lead (Pb)-Free</li> <li>solder bath temperature = 245°C</li> <li>dipping time = 5 seconds</li> <li>the number of times = once</li> <li>use of R-type flux</li> </ul>	Leads with over 95% solder coverage till lead forming are acceptable.

### 4. RESTRICTIONS ON PRODUCT USE

The following replaces the "RESTRICTIONS ON PRODUCT USE" on page 1 of body text.

#### RESTRICTIONS ON PRODUCT USE

20070701-EN

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- For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance/Handling Precautions.

#### 5. Publication date of the datasheet

The publication date of this datasheet is printed at the lower right corner of this notification.

(Annex)

Package Dimensions

QFP100-P-1420-0.65A



#### CMOS 8-Bit Microcontroller

### TMP87PM75F

The 87PM75 is a One-Time PROM microcontroller with low-power 256 K bits (32 Kbytes) electrically programmable read only memory for the 87CH75/CM75 system evaluation. The 87PM75 is pin compatible with the 87CH75/CM75. The operations possible with the 87CH75/CM75 can be performed by writing programs to PROM. The 87PM75 can write and verify in the same way as the 7,657256AD using an adaptor socket BM11124 and an EPROM programmer.



- For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance / Handling Precautions. Odarty and reliability marking to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress.

- devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.. The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic applications (computer, TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

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- The products described in this document are subject to the foreign exchange and foreign trade laws.
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#### Pin Assignments (Top View)



#### **Pin Function**

The 87PM75 has two modes: MCU and PROM.

(1) MCU mode

In this mode, the 87PM75 is pin compatible with the 87CH75/CM75 (fix the TEST pin at low level).

(2) PROM mode		$\sim (7)$	
Pin Name (PROM mode)	Input / Output	Functions	Pin Name (MCU mode)
A14 to A12 A11 to A8 A7 to A0	Input	PROM address inputs	P32 to P30 P53 to P50 P47 to P40
D7 to D0	I/O	PROM data input/outputs	P17 to P10
CE		Chip enable signal input (active low)	PO3
ŌĒ	Input	Output enable signal input (active low)	P04
VPP VCC GND	Power supply	+ 12.5 V / 5 V (Program supply voltage) + 5 V	VDD VSS
P57 to P54 P05, P02, P01 P21 P07, P06, P00	1/0	Pull-up with resistance for input processing PROM mode setting pin. Be fixed at high level.	
P22, P20 RESET		PROM mode setting pin. Be fixed at low level.	
XIN	Input	Connect an 8 MHz oscillator to stabilize the internal s	tate
XOUT	Output		tate.
PF2 to PF0 PE7 to PE0 PD7 to PD0			
P97 to P90 P87 to P80 P77 to P70		Open	
P67 to P60 VKK VAREF	Powersupply	0 V (GND)	
VASS			

#### **OPERATIONAL DESCRIPTION**

The following explains the 87PM75 hardware configuration and operation. The configuration and functions of the 87PM75 are the same as those of the 87CH75/M75, except in that a one-time PROM is used instead of an on-chip mask ROM.

The 87PM75 is placed in the *single-clock* mode during reset. To use the dual-clock mode, the low-frequency oscillator should be turned on by executing [SET (SYSCR2). XTEN] instruction at the beginning of the program.

#### 1. OPERATING MODE

The 87PM75 has two modes: MCU and PROM.

#### 1.1 MCU Mode

The MCU mode is activated by fixing the TEST / VPP pin at low level

In the MCU mode, operation is the same as with the 87CH75/M75 (the TEST / VPP pin cannot be used open because it has no built-in pull-down resistance).

#### 1.1.1 Program Memory

The 87PM75 has a  $32K \times 8$ -bit (addresses  $8000_{H}$ -FFFF<sub>H</sub> in the MCU mode, addresses  $0000_{H}$ -7FFF<sub>H</sub> in the PROM mode) of program memory (OTP).

The use the 87PM75 as the system evaluation for the 87CH75/CM75, the program should be writen to the program memory area as shown in Figure 1-1.



#### 1.1.2 Data Memory

The 87PM75 has an on-chip 1k  $\times$  8-bit data memory (static RAM).

#### 1.1.3 Input/Output Circuitry

(1) Control pins

The control pins of the 87PM75 are the same as those of the 87CH75/CM75 except that the TEST pin has is no built-in pull-down resistance.



Figure 1-2. TEST Pin

(2) I/O ports

The I/O circuitries of 87PM75 I/O ports are the same as the code A type I/O circuitries of the 87CH75/M75.

Whe using as an evaluator of other I/O code D, external pull-down resistors are required.



Figure 1-3. 1/O Circuitry Code and External Circuitry

#### 1.2 PROM Mode

The PROM mode is activated by setting the pins TEST, RESET and the ports P07-P00, P22-P20 as shown in Figure 1-4. The PROM mode is used to write and verify programs with a general-purpose PROM programmer. The high-speed programming mode I and II can be used for program operation. The 87PM75 is not supported an electric signature mode, so the ROM type must be set to TC57256AD. Set the adaptor socket switch to "N".





#### **1.2.1 Programming Flowchart (High-speed Programming Mode-I)**

The high-speed programming mode is achieved by applying the program voltage (+12.5V) to the VPP pin when Vcc = 6V. After the address and input data are stable, the data is programmed by applying a single 1ms program pulse to the  $\overline{CE}$  input. The programmed data is verified. If incorrect, another 1ms program pulse is applied and then the programmed data is verified. This process should be repeated (up to 25 times) until the program operates correctly. Programming for one address is ended by applying additional program pulse with width 3 times that needed for initial programming (number of programmed times x 1ms). After that, change the address and input data, and program as before. When programming has been completed, the data in all addresses should be verified with Vcc = Vpp = 5V.





#### **1.2.2 Programming Flowchart (High-speed Programming Mode-II)**

The high-speed programming mode is achieved by applying the program voltage (+ 12.75 V) to the Vpp pin when Vcc = 6.25 V. After the address and input data are stable, the data is programmed by applying a single 0.1ms program pulse to the  $\overline{CE}$  input. The programmed data is verified. If incorrect, another 0.1ms program pulse is applied and then the programmed data is verified. This process should be repeated (up to 25 times) until the program operates correctly. After that, change the address and input data, and program as before. When programming has been completed, the data in all addresses should be verified with Vcc = Vpp = 5 V.



Figure 1-6. Flowchart of High-speed Programming Mode - II

#### 1.2.3 Writing Method for General-purpose PROM Program

- (1) Adapters BM11124: TMP87PM75F
- (2) Adapter setting Switch (SW1) is set to side N.
- (3) PROM programmer specifying
  - i) PROM type is specified to TC57256AD. Writing voltage: 12.5 V (high-speed program I mode)
    - 12.75 V (high-speed program II mode)
  - ii) Data transfer (copy) (note 1)
    - In TMP87PM75, EPROM is within the addresses 0000<sub>H</sub> to 7FFF<sub>H</sub>. Data is required to be transferred (copied) to the addresses where it is possible to write. The program area in MCU mode and PROM mode is referred to "Program memory area" in Figure 1-1.

Ex. In the block transfer (copy) mode, executed as below.

ROM capacity of 32KB: transferred addresses 8000<sub>H</sub> to FFF<sub>H</sub> to addresses 0000<sub>H</sub> to 7FFF<sub>H</sub> ROM capacity of 16KB: transferred addresses C000<sub>H</sub> to FFFF<sub>H</sub> to addresses 4000<sub>H</sub> to 7FFF<sub>H</sub>

- iii) Writing address is specified. (note 1) Start address: 0000<sub>H</sub> (When ROM capacity of 16KB, start address is 4000<sub>H</sub>)
  - End address: 7FFF<sub>H</sub>

#### (4) Writing

Writing/Verifying is required to be executed in accordance with PROM programmer operating procedure.

- Note 1: The specifying method is referred to the PROM programmer description. Either write the data  $FF_H$  to addresses 0000<sub>H</sub> to  $3FFF_H$  when ROM capacity of 16KB.
- Note 2: When MCU is set to an adapter or the adapter is set to PROM programmer, a position of pin 1 must be adjusted. If the setting is reserved, MCU, the adapter and PROM program is damaged.
- Note 3: The TMP87PM75 does not support the electric signature mode (hereinafter referred to as "signature"). If the signature is used in PROM program, a device is damaged due to applying 12Y ± 0.5V to the address pin 9 (A9). The signature must not be used.

#### **Electrical Characteristics**

Absolute Maximum Rat	ings	$(V_{SS} = 0 V)$		
Parameter	Symbol	Pins	Ratings	Unit
Supply Voltage	V <sub>DD</sub>		-0.3 to 6.5	V
Program Voltage	V <sub>PP</sub>	TEST / VPP	- 0.3 to 13.0	v
Input Voltage	V <sub>IN</sub>		-0,3 to V <sub>DD</sub> + 0.3	v
Output Voltage	V <sub>OUT1</sub>	P2, P3, P4, P5, P6, XOUT, RESET	-0.3 to V <sub>DD</sub> + 0.3	v
Output voltage	V <sub>OUT3</sub>	Source open drain ports (	$V_{DD} - 40$ to $V_{DD} + 0.3$	v
	I <sub>OUT1</sub>	P15 to P17, P3, P4, P5	3.2	
Output Current (Par 1 nin)	I <sub>OUT2</sub>	P0, P10 to P14, P2	30	
Output Current (Per 1 pin)	I <sub>OUT3</sub>	P8, P9, PD, PE, PF	-,12	mA
	I <sub>OUT4</sub>	P6, P7	-25	
	$\Sigma I_{OUT1}$	P15 to P17, P3, P4, P5	60 >	
Output Current (Total)	$\Sigma I_{OUT2}$	P0, P10 to P14, P2	160	mA
	$\Sigma I_{OUT3}$	P6, P7, P8, P9, PD, PE, PF	- 200	
Power Dissipation [Topr = 25°C]	PD	Note 2	1200	mW
Soldering Temperature (time)	Tsld	$\rightarrow$	260 (10 s)	°C
Storage Temperature	Tstg		-/55 to 125	°C
Operating Temperature	Topr		– 30 to 70	°C

Note 1: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded. Note 2: Power Dissipation (PD); For PD, it is necessary to decrease 14.3 mWl<sup>o</sup>C.

Note 3: All VDDs should be connected externally for keeping the same voltage level.

Recommended O	perating	<b>Conditions</b> $(V_{SS} = 0$	V, Topr = 30	) to 70°C)			
Parameter	Symbol	( Pins		anditions	Min	Max	Unit
	$\square$		fc=8/MHz	NORMAL 1, 2 modes IDLE1, 2 modes	4.5		
Supply Voltage	VDØ		fs = 32.768 kHz	SLOW mode SLEEP mode	2.7	5.5	V
				STOP mode	2.0		
Output Voltage	V <sub>OUT3</sub>	Source open drain ports			V <sub>DD</sub> – 38	V <sub>DD</sub>	V
2~		Except hysteresis input Hysteresis input	v v	<sup>′</sup> <sub>DD</sub> ≧4.5 V	$V_{DD} \times 0.70$ $V_{DD} \times 0.75$	V <sub>DD</sub>	v
Input High Voltage	V <sub>IH3</sub>		v	′ <sub>DD</sub> <4.5 ∨	V <sub>DD</sub> ×0.90	v DD	•
Input Low Voltage	) V <sub>IL1</sub> V <sub>IL2</sub>	Except hysteresis input Hysteresis input	· v		0	V <sub>DD</sub> x 0.30 V <sub>DD</sub> x 0.25	v
	V <sub>IL3</sub>		v	′ <sub>DD</sub> <4.5∨		V <sub>DD</sub> × 0.10	
	fc		V <sub>DD</sub> =	= 4.5 V to 5.5 V	0.4	8.0	N.411-
Clock Frequency			V <sub>DD</sub> =	= 2.7 V to 5.5 V	0.4	4.2	MHz
~	fs	XTIN, XTOUT			30.0	34.0	kHz

Note 1: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

Note 2: Clock frequency fc: Supply voltage range is specified in NORMAL 1/2 mode and IDLE 1/2 mode.

D.C. Cha	racteris	tics (V <sub>SS</sub> = 0 V, Top	r = – 30 to 70°C)				
Parameter	Symbol	Pins	Conditions	Min	Тур.	Max	Unit
Hysteresis Voltage	V <sub>HS</sub>	Hysteresis input		(	) \0.9	-	V
	I <sub>IN1</sub>	TEST	V <sub>DD</sub> = 5.5 V	$\sim$	/		
In put Current	I <sub>IN2</sub>	Open drain ports, Tri-state ports	$\sim$ (7/	(A)	-	± 2	
Input Current	I <sub>IN3</sub>	RESET, STOP	V <sub>IN</sub> = 5.5 V / 0 V	$\mathcal{I}$			μA
	I <sub>IN4</sub>	PD, PE, PF ports (Note3)		-	-	80	
Input Resistance	R <sub>IN2</sub>	RESET		100	220	450	kΩ
Pull-down Resistance	R <sub>K</sub>	Source open drain ports	$V_{DD} = 5.5 V, V_{KK} = -30 V$	50	80	110	<b>K</b> 12
Output Leakage	I <sub>LO1</sub>	Sink open drain ports	$V_{DD} = 5.5 V, V_{OUT} = 5.5 V$	-	()	2	
Current	I <sub>LO2</sub>	Source open drain ports	$V_{DD} = 5.5 V, V_{OUT} = -32 V$		$\leq 1$	-2	μA
Current	I <sub>LO3</sub>	Tri-state ports	$V_{DD} = 5.5 V, V_{QUT} = 5.5 V / 0 V$	- /	$\langle - \rangle$	±2	
Output High Voltage	V <sub>OH2</sub>	Tri-state ports	$V_{DD} = 4.5 V, I_{OH} = -0.7 mA$	4(1	$) - \langle \rangle$	~-	v
Output high voltage	V <sub>OH3</sub>	P8, P9, PD, PE, PF	$V_{\rm DD} = 4.5 V_{\rm HOH} = -8  {\rm mA}$	2.4	12/	)) -	v
Output Low Voltage	V <sub>OL</sub>	Except XOUT, P0, P10 to P14, P2	$V_{DD} = 4.5 V, I_{OL} = 1.6 mA$	/	$\underline{\gamma}$	0.4	V
Output Low current	I <sub>OL3</sub>	P0, P10 to P14, P2	$V_{DD} = 4.5 V, V_{OL} = 1.0 V$		20	-	mA
Output High current	Іон	P6, P7	$V_{DD} = 4.5 V, V_{OH} = 2.4 V$	$(\neg)$	- 20	-	mA
Supply Current in			V <sub>DD</sub> = 5.5 V	>			
NORMAL 1, 2 modes			fc=8MHz	-	12	18	
Supply Current in			fs = 32.768 kHz				mA
IDLE 1, 2 modes		$\langle \langle \rangle \rangle$	V <sub>IN</sub> = 5.3 V/ 0.2 V	-	6	9	
Supply Current in	IDD		$V_{DD} = 3.0 V$				
SLOW mode	'DD		fs = 32.768 kHz	-	30	60	
Supply Current in							μA
SLEEP mode		$\overline{C}$	V <sub>IN</sub> = 2.8 V / 0.2 V	-	15	30	
Supply Current in		(( ))	$V_{DD} = 5.5 V$				
STOP mode			VIN=5.3V/0.2V	_	0.5	10	μA

Note 1: Typical values show those at Topr =  $25^{\circ}$ ,  $V_{DD} = 5 V$ . 7 Note 2: Input Current IIN1 IIN3; The current through resistor is not included, when the input resistor (pull-up/pull-down) is contained.

Parameter	Symbol	Conditions	Min	Тур.	Max	Uni
	V <sub>AREF</sub>		V <sub>DD</sub> – 1.5	—	V <sub>DD</sub>	.,
Analog Reference Voltage	V <sub>ASS</sub> <	V <sub>AREF</sub> – V <sub>ASS</sub> ≧ 2.5 V		V <sub>SS</sub>		- v
Analog Input Voltage	VAIN		V <sub>ASS</sub>	—	V <sub>AREF</sub>	V
Analog Supply Current	REF	V <sub>AREF</sub> = 5.5 V, V <sub>ASS</sub> = 0.0 V	—	0.5	1.0	mA
Nonlinearity Error	$\land \bigcirc$	2)	-	_	± 1	
Zero Point Error	$\sim$	$V_{DD} = 5.0 V, V_{SS} = 0.0 V$	-	_	± 1	]
Full Scale Error	$\rightarrow$	V <sub>AREF</sub> = 5.000 V V <sub>ASS</sub> = 0.000 V	-	_	± 1	LSE
Total Error			_	_	± 2	1

Note: Quantizing error is not contained in those errors.

Parame	eter	Symbol	C.	onditions	Min	Тур.	Max	Unit
			In NORMAL1, 2 modes		0.5	(())	> 10	
Machine Cycle Time			In IDLE1, 2 mo	des	0.5		10	
		t <sub>cy</sub>	In SLOW mode	)		7/5		μs
			In SLEEP mode		117.6	$\bigcirc$	133.3	
High Level Clock P	gh Level Clock Pulse Width w Level Clock Pulse Width		For external cl		50	<u> </u>	_	ns
Low Level Clock P			(XIN input), fc	= 8 MHz		<u>۲</u>		113
High Level Clock Pulse Width		t <sub>WSH</sub>	For external cl		14.7	_		μs
Low Level Clock P	ulse Width	t <sub>WSL</sub>	(XTIN input), f	s = 32.768 kHz			$\langle / \rangle$	
Recommended	l Oscillating	Conditio	u <b>ns</b> (V <sub>SS</sub> = 0 \	$V, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, \text{ T}$	opr = - 30 to	70°C)	$\mathcal{O}$	
Parameter	Oscillator	.	Oscillation	Recommended O	scillator	Recomm	Recommended Consta	
Farameter	Oscillator		Frequency			C <sub>1</sub>	C	2
High-frequency Oscillation	Ceramic Resor	nator	4 MHz 8 MHz	MURATA CSA	4.01/15 4:001/1G 3 8.0000	30pF	30	рF
	Crystal Oscill	ator	41/Hz	TOYOCOM 204B 4.0000		20pF	20	рF
Low-frequency Oscillation	Crystal Oscill.	ator	32.768 kHz	MX-	38⊤	15pF	15	рF
			on	> ⊂1		C <sub>2</sub>	ı	



#### (2) High-Speed Programming Operation (Topr = $25 \pm 5^{\circ}$ C)

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input High Voltage	V <sub>IH4</sub>		V <sub>CC</sub> × 0.7	f	Vcc	V
Input Low Voltage	V <sub>IL4</sub>		0		V <sub>CC</sub> × 0.12	~
Power Supply Voltage	V <sub>CC</sub>		5.75	6.0	6.25	v
Program Power Supply Voltage	V <sub>PP</sub>		12.0	12.5	13.0	V
Initial Program Pulse Width	t <sub>PW</sub>	V <sub>CC</sub> = 6.0 V ± 0.25 V V <sub>PP</sub> = 12.5 ± 0.25 V	0.95	1.0	1.05	ms



Note1:	When $V_{cc}$ power supply is turned on or after, $V_{pp}$ must be increased.
	When V <sub>sc</sub> power supply is turned off or before, V <sub>pp</sub> must be decreased.
Note2:	The device must not be set to the EPROM programmer or picked up from it under applying
	the program voltage (12.75 V $\pm$ 0.5 V) to the V <sub>pp</sub> pin as the device is damaged.
Note3:	Be sure to execute the recommended programing mode with the recommended programing
	adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.
	Timing Waveforms of Programming Operation

Timing Waveforms of Programming Operation

	Symbol	Conditions	Min	Тур.	Max	Unit
nput High Voltage	V <sub>IH4</sub>		V <sub>CC</sub> x 0.7	f	Vcc	v
nput Low Voltage	V <sub>IL4</sub>		0		V <sub>CC</sub> × 0.12	v
upply Voltage	V <sub>CC</sub>		6.00	6,25	6.50	ν
rogram Supply Voltage	V <sub>PP</sub>		12.50	12.75	13.0	ν
nitial Program Pulse Width	t <sub>PW</sub>	V <sub>CC</sub> = 6.0 V ± 0.25 V V <sub>PP</sub> = 12.5 ± 0.25 V	0.095	0.1	0.105	ms
A14 to A0		Input Output Program verify Internal program				
Note1: When V <sub>cc</sub> powe	r supply i	s turned on or after, V <sub>pp</sub> n s turned off or before, V <sub>pj</sub> set to the EPROM program	<sub>o</sub> must be de	creased.	, it under er	nolvív

#### (3) Program Operation (High speed write mode -II) (Topr = $25 \pm 5^{\circ}$ C)